



www.centralsemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR 2N5820 series devices are epoxy molded complementary silicon small signal transistors manufactured by the epitaxial planar process designed for general purpose amplifier applications where a high collector current rating is required.

MARKING: FULL PART NUMBER

MAXIMUM RATINGS: (T_A=25°C unless otherwise noted)

	50 H0(00)		
	SYMBOL		UNITS
Collector-Base Voltage	V _{CBO}	70	V
Collector-Emitter Voltage	VCES	70	V
Collector-Emitter Voltage	V _{CEO}	60	V
Emitter-Base Voltage	V _{EBO}	5.0	V
Continuous Collector Current	۱ _C	750	mA
Peak Collector Current	ICM	1.0	А
Power Dissipation	PD	625	mW
Power Dissipation (T _C =25°C)	PD	1.5	W
Operating and Storage Junction Temperature	TJ, Tstg	-65 to +150	°C
Thermal Resistance	Θ_{JA}	200	°C/W
Thermal Resistance	ΘJC	83.3	°C/W

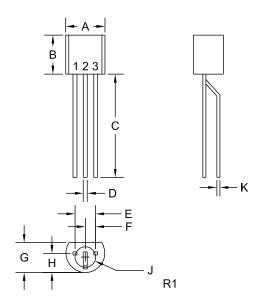
ELECTRICAL CHARACTERISTICS: (T_A=25°C unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
ICBO	V _{CB} =25V		100	nA
ICBO	V _{CB} =25V, T _A =100°C		15	μΑ
IEBO	V _{EB} =5.0V		10	μΑ
BVCES	Ι _C =10μΑ	70		V
BVCEO	I _C =10mA	60		V
BVEBO	I _E =10μA	5.0		V
V _{CE} (SAT)	I _C =500mA, I _B =50mA		0.75	V
V _{BE} (SAT)	I _C =500mA, I _B =50mA		1.2	V
V _{BE(ON)}	V _{CE} =2.0V, I _C =500mA	0.6	1.1	V
h _{FE}	V _{CE} =2.0V, I _C =2.0mA (2N5820, 21)	60	120	
h _{FE}	V _{CE} =2.0V, I _C =2.0mA (2N5822, 23)	100	250	
h _{FE}	V _{CE} =2.0V, I _C =500mA (2N5820, 21)	20		
h _{FE}	V _{CE} =2.0V, I _C =500mA (2N5822, 23)	25		
fT	V _{CE} =2.0V, I _C =50mA, f=20MHz (2N5820, 21)	100		MHz
fT	V _{CE} =2.0V, I _C =50mA, f=20MHz (2N5822, 23)	120		MHz
Cob	V _{CB} =10V, I _C =0, f=1.0MHz		15	pF
Cib	V _{EB} =0.5V, I _E =0, f=1.0MHz		55	pF
				R2 (17-November 2014)





COMPLEMENTARY SILICON TRANSISTORS



DIMENSIONS						
	INCHES		MILLIMETERS			
SYMBOL	MIN	MAX	MIN	MAX		
A (DIA)	0.175	0.205	4.45	5.21		
В	0.170	0.210	4.32	5.33		
С	0.500	-	12.70	-		
D	0.016	0.022	0.41	0.56		
Е	0.100 0.050		2.54			
F			1.27			
G	0.125	0.165	3.18	4.19		
Н	0.080	0.105	2.03	2.67		
J (DIA)	0.100		2.54			
K	0.015		0.38			
TO-92-18R (REV: R1)						

LEAD CODE:

Collector
Base
Emitter

TO-92-18R CASE - MECHANICAL OUTLINE

MARKING: FULL PART NUMBER

www.centralsemi.com

R2 (17-November 2014)

OUTSTANDING SUPPORT AND SUPERIOR SERVICES

PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free guick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- · Environmental regulation compliance
- Customer specific screening
- · Up-screening capabilities

· Custom product packing

Custom bar coding for shipments

- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits
- · Custom product and package development

REQUESTING PRODUCT PLATING

- If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when 1. ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix " PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

Corporate Headquarters & Customer Support Team

Central Semiconductor Corp. 145 Adams Avenue Hauppauge, NY 11788 USA Main Tel: (631) 435-1110 Main Fax: (631) 435-1824 Support Team Fax: (631) 435-3388 www.centralsemi.com

Worldwide Field Representatives: www.centralsemi.com/wwreps

Worldwide Distributors: www.centralsemi.com/wwdistributors

For the latest version of Central Semiconductor's LIMITATIONS AND DAMAGES DISCLAIMER. which is part of Central's Standard Terms and Conditions of sale, visit: www.centralsemi.com/terms



Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Central Semiconductor: 2N5822 2N5822 TIN/LEAD